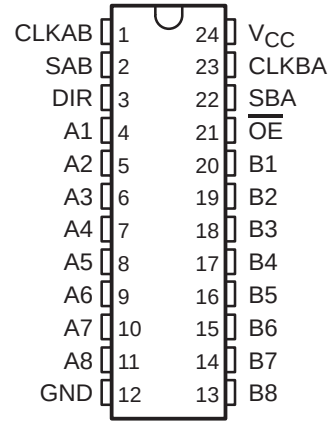
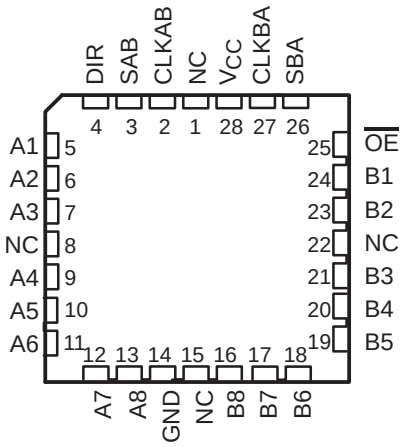
- **Independent Registers for A and B Buses**
- **Multiplexed Real-Time and Stored Data**
- **Choice of True or Inverting Data Paths**
- **Choice of 3-State or Open-Collector Outputs**
- **Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (NT) and Ceramic (JT) 300-mil DIPs**

DEVICE	OUTPUT	LOGIC
SN54ALS646, SN74ALS646A, ′AS646	3 state	True
SN54ALS648, SN74ALS648A, SN74AS648	3 state	Inverting

SN54ALS646, SN54ALS648, SN54AS646 . . . JT PACKAGE
SN74ALS646A, SN74ALS648A, SN74AS646,
SN74AS648 . . . DW OR NT PACKAGE
(TOP VIEW)



SN54ALS646, SN54ALS648, SN54AS646 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

description

These devices consist of bus-transceiver circuits with 3-state or open-collector outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Data on the A or B bus is clocked into the registers on the low-to-high transition of the appropriate clock (CLKAB or CLKBA) input. Figure 1 illustrates the four fundamental bus-management functions that can be performed with the octal bus transceivers and registers.

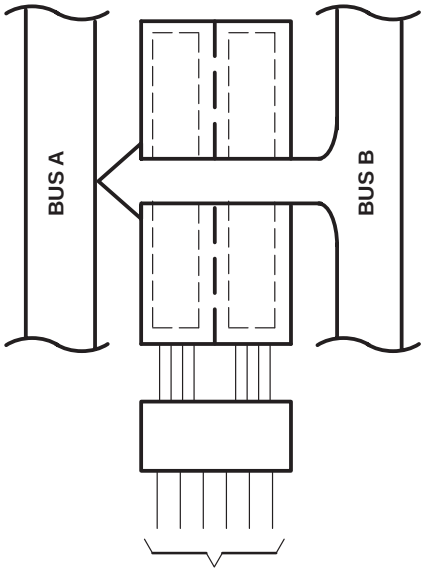
Output-enable ($\overline{OE}$) and direction-control (DIR) inputs control the transceiver functions. In the transceiver mode, data present at the high-impedance port may be stored in either or both registers.

The select-control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode) data. The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. DIR determines which bus receives data when $\overline{OE}$ is low. In the isolation mode ($\overline{OE}$ high), A data may be stored in one register and/or B data may be stored in the other register.

When an output function is disabled, the input function is still enabled and can be used to store and transmit data. Only one of the two buses, A or B, may be driven at a time.

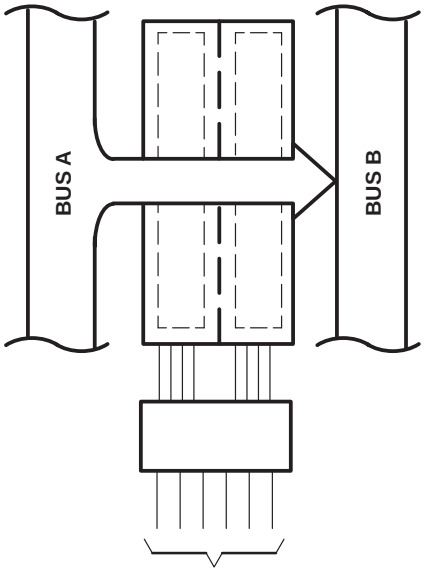
The -1 version of the SN74ALS646A is identical to the standard version, except that the recommended maximum I_{OL} in the -1 version is increased to 48 mA. There are no -1 versions of the SN54ALS646, SN54ALS648, or SN74ALS648A.

The SN54ALS646, SN54ALS648, and SN54AS646 are characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ALS646A, SN74ALS648A, SN74AS646, and SN74AS648 are characterized for operation from 0°C to 70°C.



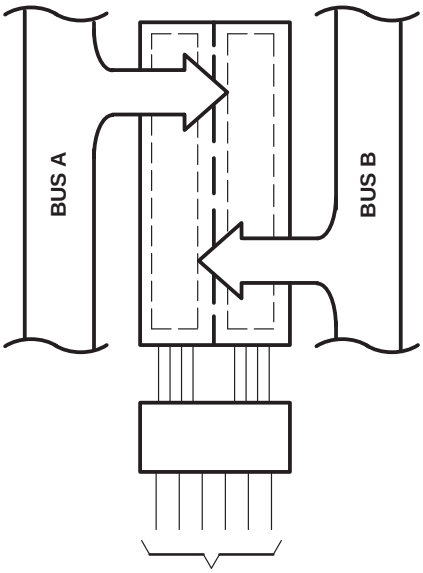
21 $\overline{OE}$	3 DIR	1 CLKAB	23 CLKBA	2 SAB	22 SBA
L	L	X	X	X	L

REAL-TIME TRANSFER BUS B TO BUS A



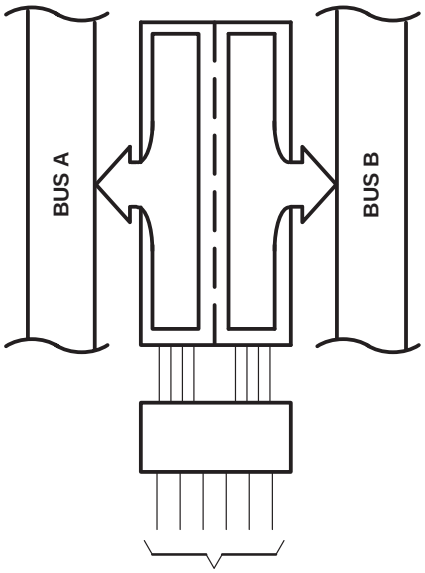
21 $\overline{OE}$	3 DIR	1 CLKAB	23 CLKBA	2 SAB	22 SBA
L	H	X	X	L	X

REAL-TIME TRANSFER BUS A TO BUS B



21 $\overline{OE}$	3 DIR	1 CLKAB	23 CLKBA	2 SAB	22 SBA
X	X	↑	X	X	X
X	X	X	↑	X	X
H	X	↑	↑	X	X

STORAGE FROM A, B, OR A AND B



21 $\overline{OE}$	3 DIR	1 CLKAB	23 CLKBA	2 SAB	22 SBA
L	L	X	H or L	X	H
L	H	H or L	X	H	X

TRANSFER STORED DATA TO A AND/OR B

Figure 1. Bus-Management Functions

Pin numbers shown are for the DW, JT, and NT packages.

Function Tables

SN54ALS646, SN54AS646, SN74ALS646A, SN74AS646

INPUTS						DATA I/O		OPERATION OR FUNCTION
$\overline{OE}$	DIR	CLKAB	CLKBA	SAB	SBA	A1–A8	B1–B8	
X	X	↑	X	X	X	Input	Unspecified†	Store A, B unspecified†
X	X	X	↑	X	X	Unspecified†	Input	Store B, A unspecified†
H	X	↑	↑	X	X	Input	Input	Store A and B data
H	X	H or L	H or L	X	X	Input disabled	Input disabled	Isolation, hold storage
L	L	X	X	X	L	Output	Input	Real-time B data to A bus
L	L	X	H or L	X	H	Output	Input	Stored B data to A bus
L	H	X	X	L	X	Input	Output	Real-time A data to B bus
L	H	H or L	X	H	X	Input	Output	Stored A data to B bus

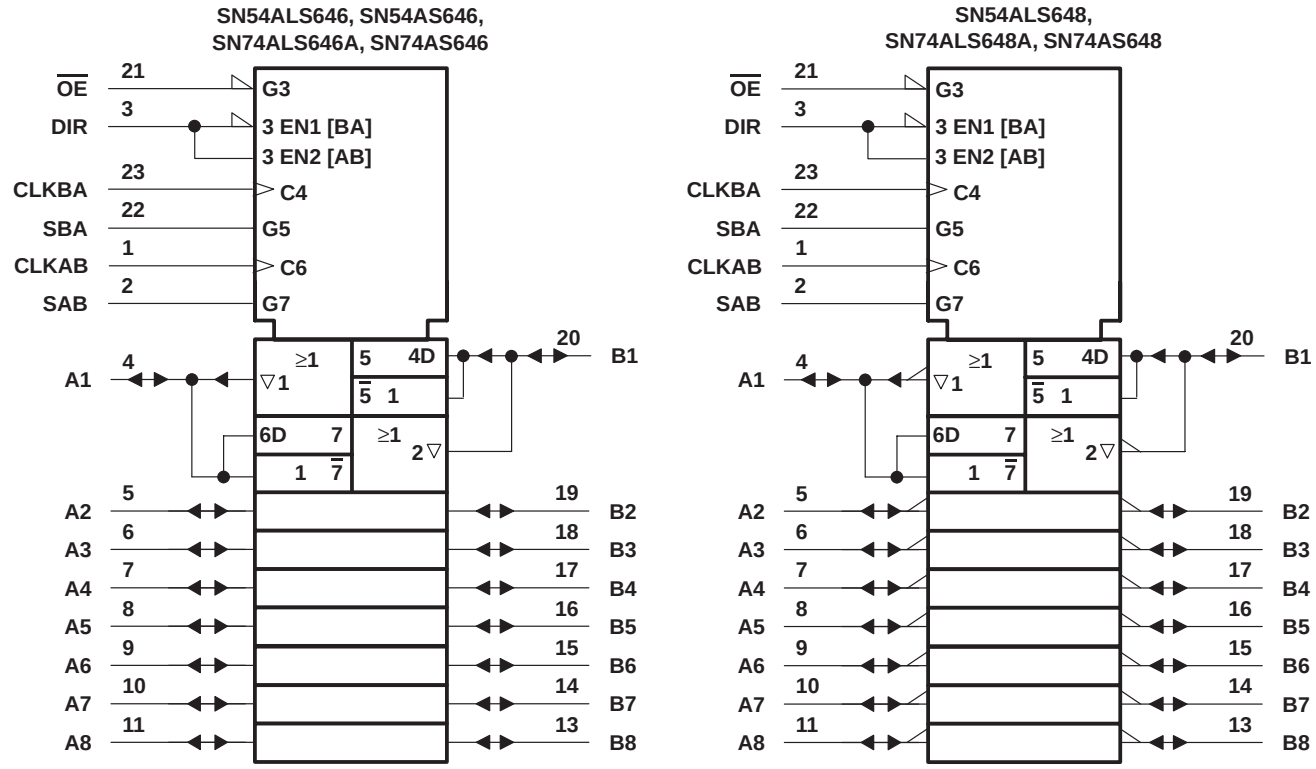
† The data output functions can be enabled or disabled by various signals at $\overline{OE}$ and DIR. Data input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.

SN54ALS648, SN74ALS648A, SN74AS648

INPUTS						DATA I/O		OPERATION OR FUNCTION
$\overline{OE}$	DIR	CLKAB	CLKBA	SAB	SBA	A1–A8	B1–B8	
X	X	↑	X	X	X	Input	Unspecified†	Store A, B unspecified†
X	X	X	↑	X	X	Unspecified†	Input	Store B, A unspecified†
H	X	↑	↑	X	X	Input	Input	Store A and B data
H	X	H or L	H or L	X	X	Input disabled	Input disabled	Isolation, hold storage
L	L	X	X	X	L	Output	Input	Real-time $\overline{B}$ data to A bus
L	L	X	H or L	X	H	Output	Input	Stored $\overline{B}$ data to A bus
L	H	X	X	L	X	Input	Output	Real-time $\overline{A}$ data to B bus
L	H	H or L	X	H	X	Input	Output	Stored $\overline{A}$ data to B bus

† The data output functions can be enabled or disabled by various signals at $\overline{OE}$ and DIR. Data input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.

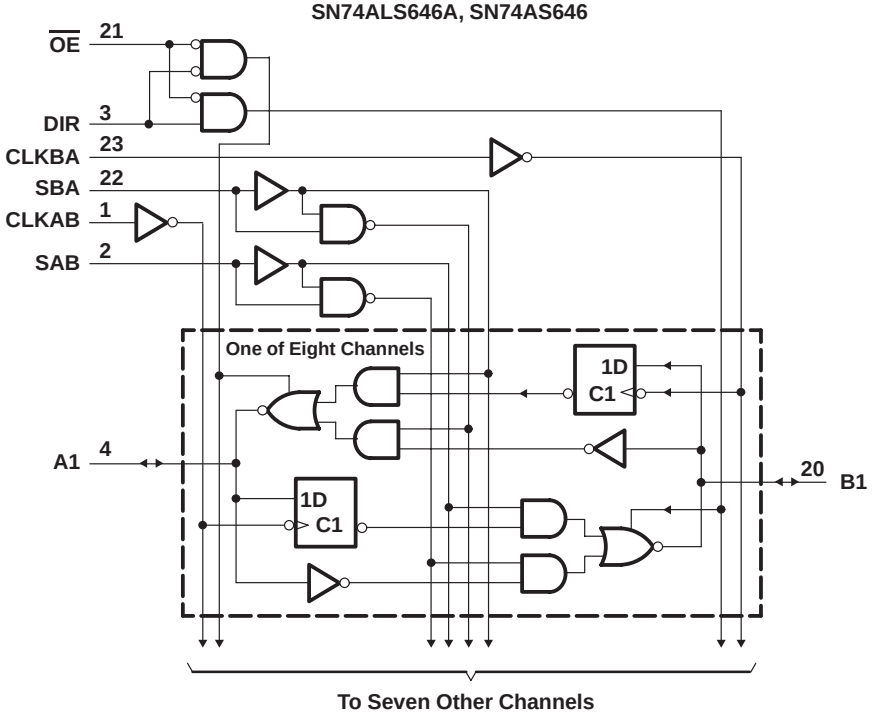
logic symbols†



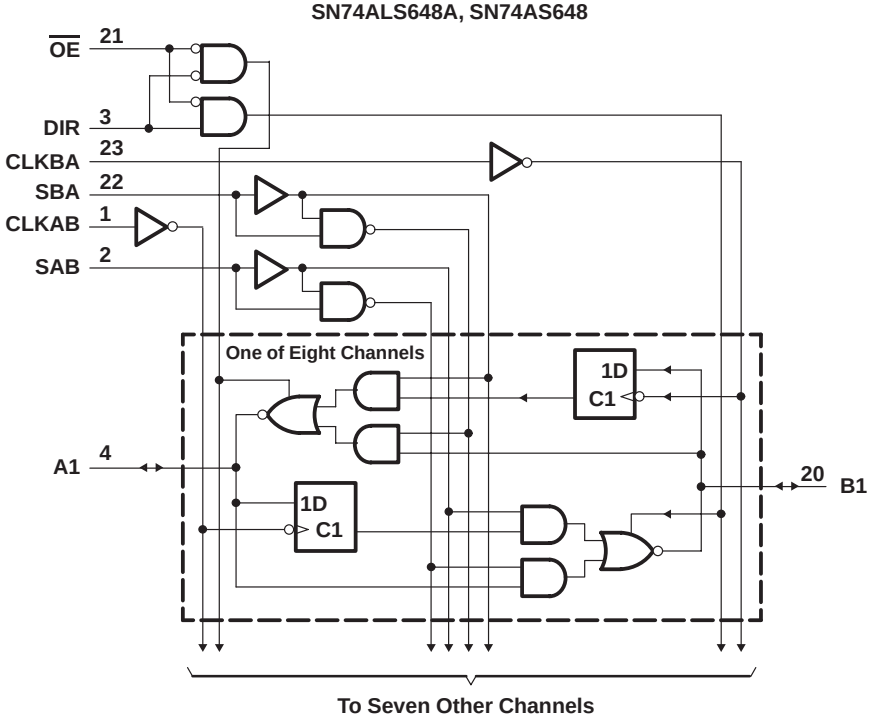
† These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for the DW, JT, and NT packages.

logic diagrams (positive logic)

**SN54ALS646, SN54AS646,
SN74ALS646A, SN74AS646**



**SN54ALS648,
SN74ALS648A, SN74AS648**



Pin numbers shown are for the DW, JT, and NT packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} . . . . . 7 V
Input voltage, V_I: Control inputs . . . . . 7 V
I/O ports . . . . . 5.5 V
Operating free-air temperature range, T_A: SN54ALS646 . . . . . −55°C to 125°C
SN74ALS646A . . . . . 0°C to 70°C
Storage temperature range . . . . . −65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN54ALS646			SN74ALS646A			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.7			0.8	V
I_{OH}	High-level output current			−12			−15	mA
I_{OL}	Low-level output current			12			24	mA
							48‡	
f_{clock}	Clock frequency	0		35	0		40	MHz
t_w	Pulse duration, CLKBA or CLKAB high or low	14.5			12.5			ns
t_{su}	Setup time, A before CLKAB↑ or B before CLKBA↑	15			10			ns
t_h	Hold time, A after CLKAB↑ or B after CLKBA↑	0			0			ns
T_A	Operating free-air temperature	−55		125	0		70	°C

‡ Applies only to the -1 version and only if V_{CC} is maintained between 4.75 V and 5.25

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54ALS646			SN74ALS646A			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
V_{IK}		V_{CC} = 4.5 V,	I_I = –18 mA			–1.2			–1.2	V
V_{OH}		V_{CC} = 4.5 V to 5.5 V,	I_{OH} = –0.4 mA	V_{CC}–2			V_{CC}–2			V
		V_{CC} = 4.5 V	I_{OH} = –3 mA	2.4	3.2		2.4	3.2		
			I_{OH} = –12 mA	2						
			I_{OH} = –15 mA				2			
V_{OL}		V_{CC} = 4.5 V	I_{OL} = 12 mA		0.25	0.4		0.25	0.4	V
			I_{OL} = 24 mA					0.35	0.5	
			I_{OL} = 48 mA‡					0.35	0.5	
I_I	Control inputs	V_{CC} = 5.5 V	V_I = 7 V			0.1			0.1	mA
	A or B ports		V_I = 5.5 V			0.1			0.1	
I_{IH}	Control inputs	V_{CC} = 5.5 V,	V_I = 2.7 V			20			20	µA
	A or B ports§					20			20	
I_{IL}	Control inputs	V_{CC} = 5.5 V,	V_I = 0.4 V			–0.2			–0.2	mA
	A or B ports§					–0.2			–0.2	
I_O¶		V_{CC} = 5.5 V,	V_O = 2.25 V	–20		–112	–30		–112	mA
I_{CC}		V_{CC} = 5.5 V	Outputs high		47	76		47	76	mA
			Outputs low		55	88		55	88	
			Outputs disabled		55	88		55	88	

† All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ Applies only to the -1 version and only if V_{CC} is maintained between 4.75 V and 5.25
§ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.
¶ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS}.

switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T_A = MIN to MAX†				UNIT
			SN54ALS646		SN74ALS646A		
			MIN	MAX	MIN	MAX	
f_{max}			35		40		MHz
t_{PLH}	CLKBA or CLKAB	A or B	10	35	7	30	ns
t_{PHL}			5	20	5	17	
t_{PLH}	A or B	B or A	5	22	3	20	ns
t_{PHL}			3	15	3	12	
t_{PLH}	SBA or SAB‡ (stored data low)	A or B	10	40	7	35	ns
t_{PHL}			5	23	5	20	
t_{PLH}	SBA or SAB‡ (stored data high)	A or B	8	30	6	25	ns
t_{PHL}			5	24	5	20	
t_{PZH}	$\overline{OE}$	A or B	3	20	2	17	ns
t_{PZL}			5	22	4	20	
t_{PHZ}	$\overline{OE}$	A or B	1	12	1	10	ns
t_{PLZ}			1	20	2	16	
t_{PZH}	DIR	A or B	5	38	3	30	ns
t_{PZL}			5	30	4	25	
t_{PHZ}	DIR	A or B	1	12	1	10	ns
t_{PLZ}			2	21	2	16	

† For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.
‡ These parameters are measured with the internal output state of the storage register opposite that of the bus input.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} . . . . . 7 V
Input voltage, V_I: Control inputs . . . . . 7 V
I/O ports . . . . . 5.5 V
Operating free-air temperature range, T_A: SN54ALS648 . . . . . −55°C to 125°C
SN74ALS648A . . . . . 0°C to 70°C
Storage temperature range . . . . . −65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN54ALS648			SN74ALS648A			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.7			0.8	V
I_{OH}	High-level output current			−12			−15	mA
I_{OL}	Low-level output current			12			24	mA
f_{clock}	Clock frequency	0		35	0		40	MHz
t_w	Pulse duration, CLKBA or CLKAB high or low	14.5			12.5			ns
t_{su}	Setup time, A before CLKAB↑ or B before CLKBA↑	15			10			ns
t_h	Hold time, A after CLKAB↑ or B after CLKBA↑	0			0			ns
T_A	Operating free-air temperature	−55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54ALS648			SN74ALS648A			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
V_{IK}		V_{CC} = 4.5 V,	I_I = –18 mA			–1.2			–1.2	V
V_{OH}		V_{CC} = 4.5 V to 5.5 V,	I_{OH} = –0.4 mA	V_{CC}–2			V_{CC}–2			V
		V_{CC} = 4.5 V	I_{OH} = –3 mA	2.4	3.2		2.4	3.2		
			I_{OH} = –12 mA	2						
			I_{OH} = –15 mA				2			
V_{OL}		V_{CC} = 4.5 V	I_{OL} = 12 mA		0.25	0.4		0.25	0.4	V
			I_{OL} = 24 mA					0.35	0.5	
I_I	Control inputs	V_{CC} = 5.5 V	V_I = 7 V			0.1			0.1	mA
	A or B ports		V_I = 5.5 V			0.1			0.1	
I_{IH}	Control inputs	V_{CC} = 5.5 V,	V_I = 2.7 V			20			20	µA
	A or B ports‡					20			20	
I_{IL}	Control inputs	V_{CC} = 5.5 V,	V_I = 0.4 V			–0.2			–0.2	mA
	A or B ports‡					–0.2			–0.2	
I_O§		V_{CC} = 5.5 V,	V_O = 2.25 V	–20		–112	–30		–112	mA
I_{CC}		V_{CC} = 5.5 V	Outputs high		47	76		47	76	mA
			Outputs low		57	88		57	88	
			Outputs disabled		57	88		57	88	

† All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.
§ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS}.

switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T_A = MIN to MAX†				UNIT
			SN54ALS648		SN74ALS648A		
			MIN	MAX	MIN	MAX	
f_{max}			35		40		MHz
t_{PLH}	CLKBA or CLKAB	A or B	8	39	7	33	ns
t_{PHL}			5	23	5	20	
t_{PLH}	A or B	B or A	3	20	2	17	ns
t_{PHL}			2	12	2	10	
t_{PLH}	SBA or SAB‡ (stored data low)	A or B	5	44	5	39	ns
t_{PHL}			4	26	4	22	
t_{PLH}	SBA or SAB‡ (stored data high)	A or B	6	30	6	25	ns
t_{PHL}			6	25	6	21	
t_{PZH}	$\overline{OE}$	A or B	4	25	2	22	ns
t_{PZL}			4	25	4	22	
t_{PHZ}	$\overline{OE}$	A or B	1	12	1	10	ns
t_{PLZ}			2	21	2	15	
t_{PZH}	DIR	A or B	4	35	2	27	ns
t_{PZL}			3	25	3	19	
t_{PHZ}	DIR	A or B	1	17	1	14	ns
t_{PLZ}			2	22	2	15	

† For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.
‡ These parameters are measured with the internal output state of the storage register opposite that of the bus input.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} . . . . . 7 V
Input voltage, V_I: Control inputs . . . . . 7 V
I/O ports . . . . . 5.5 V
Operating free-air temperature range, T_A: SN54AS646 . . . . . –55°C to 125°C
SN74AS646 . . . . . 0°C to 70°C
Storage temperature range . . . . . –65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			SN54AS646			SN74AS646			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage		2			2			V
V_{IL}	Low-level input voltage				0.8			0.8	V
I_{OH}	High-level output current				–12			–15	mA
I_{OL}	Low-level output current				32			48	mA
f_{clock}*	Clock frequency		0		75	0		90	MHz
t_w*	Pulse duration	CLKBA or CLKAB high	6			5			ns
		CLKBA or CLKAB low	7			6			
t_{su}*	Setup time, A before CLKAB↑ or B before CLKBA↑		7			6			ns
t_h*	Hold time, A after CLKAB↑ or B before CLKBA		0			0			ns
T_A	Operating free-air temperature		–55		125	0		70	°C

* On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54AS646			SN74AS646			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
V_{IK}		V_{CC} = 4.5 V,	I_I = –18 mA			–1.2			–1.2	V
V_{OH}		V_{CC} = 4.5 V to 5.5 V,	I_{OH} = –2 mA	V_{CC}–2			V_{CC}–2			V
		V_{CC} = 4.5 V	I_{OH} = –3 mA	2.4	3.2		2.4	3.2		
			I_{OH} = –12 mA	2						
			I_{OH} = –15 mA				2			
V_{OL}		V_{CC} = 4.5 V	I_{OL} = 32 mA		0.25	0.5				V
			I_{OL} = 48 mA					0.35	0.5	
I_I	Control inputs	V_{CC} = 5.5 V,	V_I = 7 V			0.1			0.1	mA
	A or B ports	V_{CC} = 5.5 V,	V_I = 5.5 V			0.1			0.1	
I_{IH}	Control inputs	V_{CC} = 5.5 V,	V_I = 2.7 V			20			20	µA
	A or B ports‡					70			70	
I_{IL}	Control input	V_{CC} = 5.5 V,	V_I = 0.4 V			–0.5			–0.5	mA
	A or B ports‡					–0.75			–0.75	
I_O§		V_{CC} = 5.5 V,	V_O = 2.25 V	–30		–112	–30		–112	mA
I_{CC}		V_{CC} = 5.5 V	Outputs high		120	195		120	195	mA
			Outputs low		130	211		130	211	
			Outputs disabled		130	211		130	211	

† All typical values are at V_{CC} = 5 V, T_A = 25 °C.
‡ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.
§ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS}.

switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T_A = MIN to MAX†				UNIT
			SN54AS646		SN74AS646		
			MIN	MAX	MIN	MAX	
f_{max}*			75		90		MHz
t_{PLH}	CLKBA or CLKAB	A or B	2	9.5	2	8.5	ns
t_{PHL}			2	10	2	9	
t_{PLH}	A or B	B or A	2	11.5	2	9	ns
t_{PHL}			1	8	1	7	
t_{PLH}	SBA or SAB‡	A or B	2	13.5	2	11	ns
t_{PHL}			2	11	2	9	
t_{PZH}	$\overline{OE}$	A or B	2	11	2	9	ns
t_{PZL}			3	15	3	14	
t_{PHZ}	$\overline{OE}$	A or B	2	11	2	9	ns
t_{PLZ}			2	11	2	9	
t_{PZH}	DIR	A or B	3	21	3	16	ns
t_{PZL}			3	24	3	18	
t_{PHZ}	DIR	A or B	2	12	2	10	ns
t_{PLZ}			2	12	2	10	

* On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.
† For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.
‡ These parameters are measured with the internal output state of the storage register opposite that of the bus input.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} . . . . . 7 V
Input voltage, V_I: Control inputs . . . . . 7 V
I/O ports . . . . . 5.5 V
Operating free-air temperature range, T_A: SN74AS648 . . . . . 0°C to 70°C
Storage temperature range . . . . . –65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			SN74AS648			UNIT
			MIN	NOM	MAX	
V_{CC}	Supply voltage		4.5	5	5.5	V
V_{IH}	High-level input voltage		2			V
V_{IL}	Low-level input voltage				0.8	V
I_{OH}	High-level output current				–15	mA
I_{OL}	Low-level output current				48	mA
f_{clock}	Clock frequency		0		90	MHz
t_w	Pulse duration	CLKBA or CLKAB high	5			ns
		CLKBA or CLKAB low	6			
t_{su}	Setup time, A before CLKAB↑ or B before CLKBA↑		6			ns
t_h	Hold time, A after CLKAB↑ or B before CLKBA		0			ns
T_A	Operating free-air temperature		0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN74AS648			UNIT
				MIN	TYP‡	MAX	
V_{IK}		V_{CC} = 4.5 V,	I_I = –18 mA			–1.2	V
V_{OH}		V_{CC} = 4.5 V to 5.5 V,	I_{OH} = –2 mA	V_{CC}–2			V
		V_{CC} = 4.5 V	I_{OH} = –3 mA	2.4	3.2		
			I_{OH} = –15 mA	2			
V_{OL}		V_{CC} = 4.5 V,	I_{OL} = 48 mA		0.35	0.5	V
I_I	Control inputs	V_{CC} = 5.5 V	V_I = 7 V			0.1	mA
	A or B ports		V_I = 5.5 V			0.1	
I_{IH}	Control inputs	V_{CC} = 5.5 V,	V_I = 2.7 V			20	µA
	A or B ports§					70	
I_{IL}	Control input	V_{CC} = 5.5 V,	V_I = 0.4 V			–0.5	mA
	A or B ports§					–0.75	
I_O¶		V_{CC} = 5.5 V,	V_O = 2.25 V	–30		–112	mA
I_{CC}		V_{CC} = 5.5 V	Outputs high		110	185	mA
			Outputs low		120	195	
			Outputs disabled		120	195	

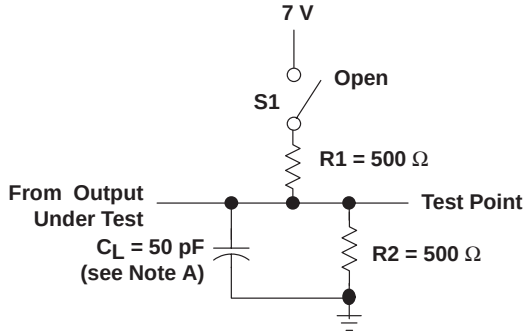
‡ All typical values are at V_{CC} = 5 V, T_A = 25 °C.
§ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.
¶ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS}.

switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T_A = MIN to MAX†		UNIT
			SN74AS648		
			MIN	MAX	
f_{max}			90		MHz
t_{PLH}	CLKBA or CLKAB	A or B	2	8.5	ns
t_{PHL}			2	9	
t_{PLH}	A or B	B or A	2	8	ns
t_{PHL}			1	7	
t_{PLH}	SBA or SAB‡	A or B	2	11	ns
t_{PHL}			2	9	
t_{PZH}	$\overline{OE}$	A or B	2	9	ns
t_{PZL}			3	15	
t_{PHZ}	$\overline{OE}$	A or B	2	9	ns
t_{PLZ}			2	9	
t_{PZH}	DIR	A or B	3	16	ns
t_{PZL}			3	18	
t_{PHZ}	DIR	A or B	2	10	ns
t_{PLZ}			2	10	

† For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.
‡ These parameters are measured with the internal output state of the storage register opposite that of the bus input.

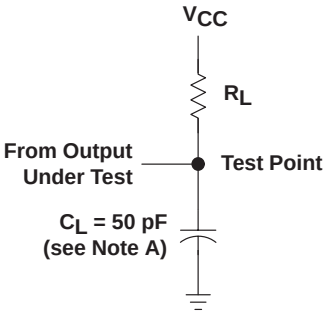
PARAMETER MEASUREMENT INFORMATION



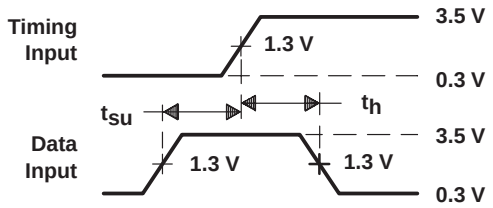
LOAD CIRCUIT
FOR 3-STATE OUTPUTS

SWITCH POSITION TABLE

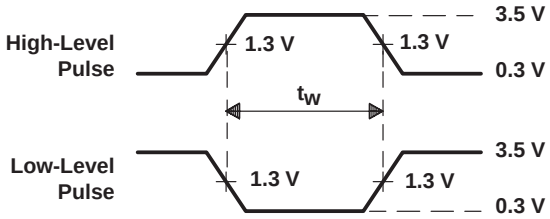
TEST	S1
t_{PLH}	Open
t_{PHL}	Open
t_{PZH}	Open
t_{PZL}	Closed
t_{PHZ}	Open
t_{PLZ}	Closed



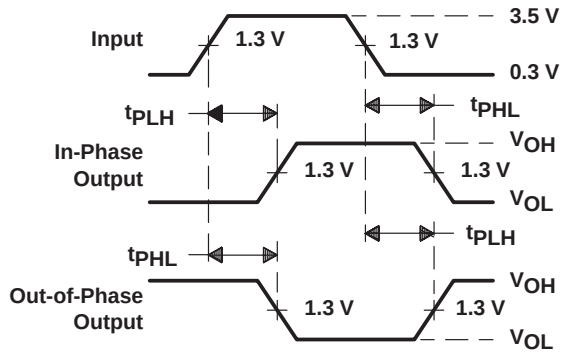
LOAD CIRCUIT
FOR OPEN-COLLECTOR OUTPUTS



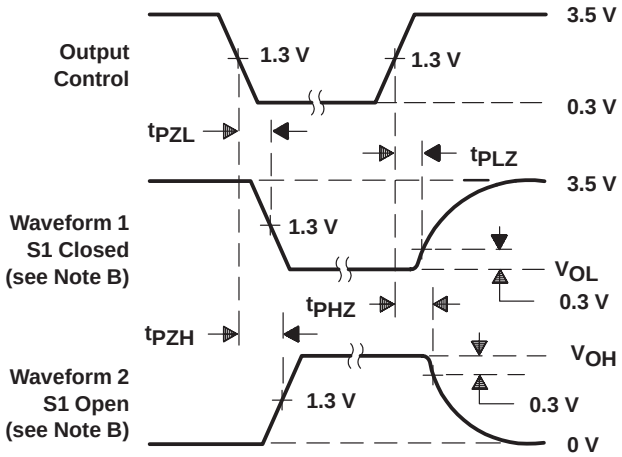
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES, 3-STATE OUTPUTS

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_r ≤ 2 ns, t_f ≤ 2 ns.
D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuits and Voltage Waveforms

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8759501LA	ACTIVE	CDIP	JT	24	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8759501LA SNJ54AS646JT	Samples
5962-8995601LA	ACTIVE	CDIP	JT	24	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8995601LA SNJ54ALS646JT	Samples
5962-9052301LA	ACTIVE	CDIP	JT	24	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9052301LA SNJ54ALS648JT	Samples
SN74ALS646ADW	ACTIVE	SOIC	DW	24	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ALS646A	Samples
SN74ALS646ADWR	ACTIVE	SOIC	DW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ALS646A	Samples
SN74ALS648ADW	ACTIVE	SOIC	DW	24	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ALS648A	Samples
SN74AS646DW	ACTIVE	SOIC	DW	24	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS646	Samples
SNJ54ALS646JT	ACTIVE	CDIP	JT	24	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8995601LA SNJ54ALS646JT	Samples
SNJ54ALS648JT	ACTIVE	CDIP	JT	24	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9052301LA SNJ54ALS648JT	Samples
SNJ54AS646JT	ACTIVE	CDIP	JT	24	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8759501LA SNJ54AS646JT	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

OTHER QUALIFIED VERSIONS OF SN54AS646, SN74AS646 :

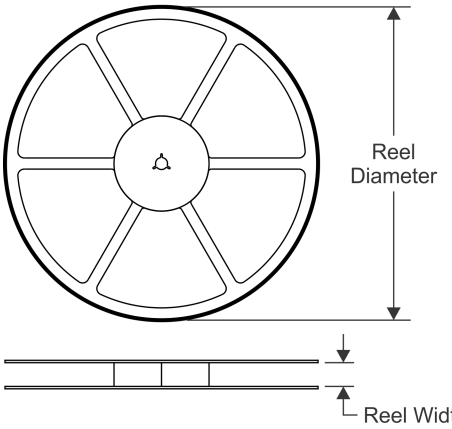
- Catalog : SN74AS646
- Military : SN54AS646

NOTE: Qualified Version Definitions:

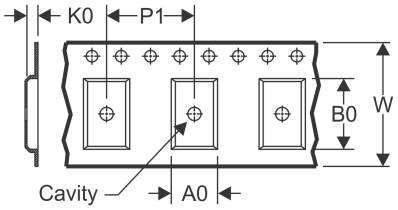
- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

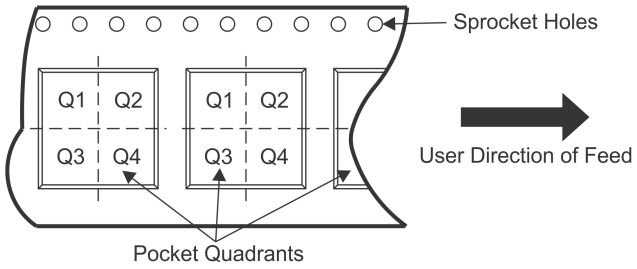


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

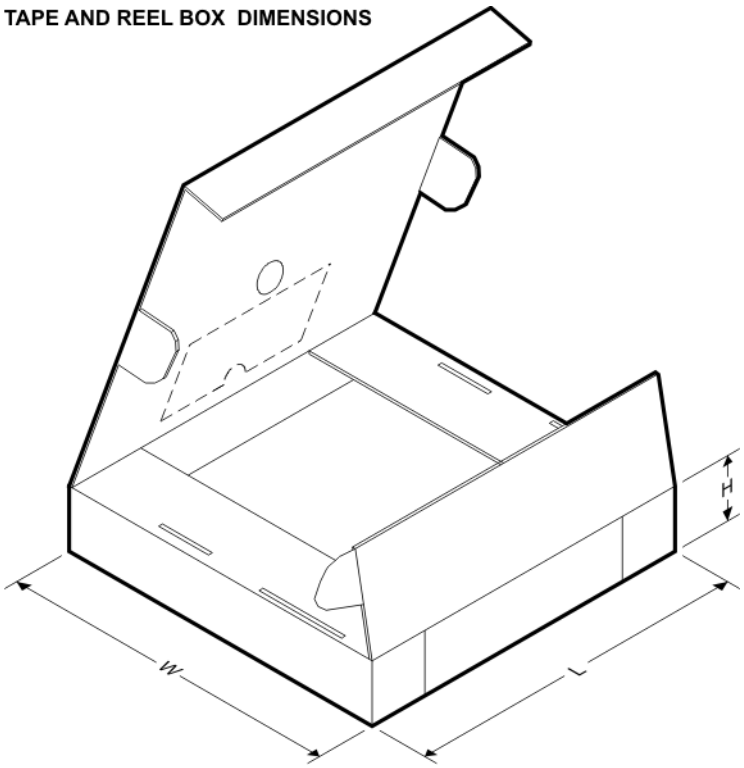
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALS646ADWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

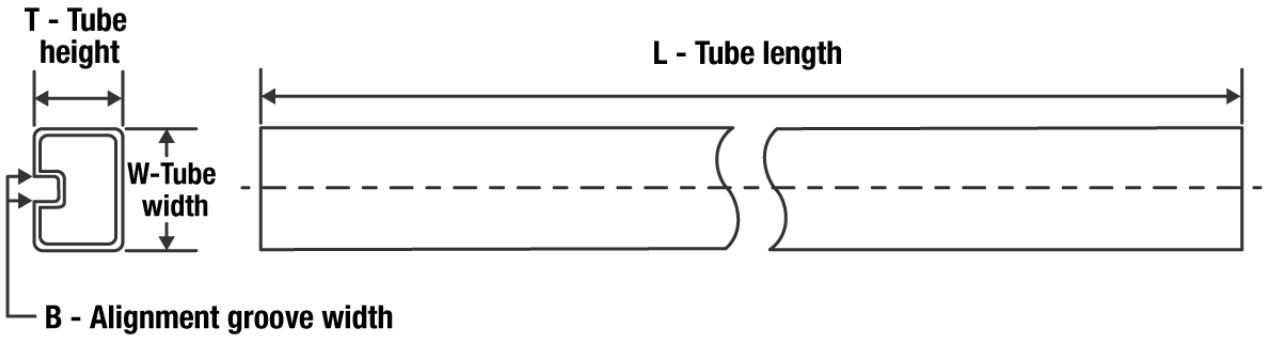
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALS646ADWR	SOIC	DW	24	2000	350.0	350.0	43.0

TUBE



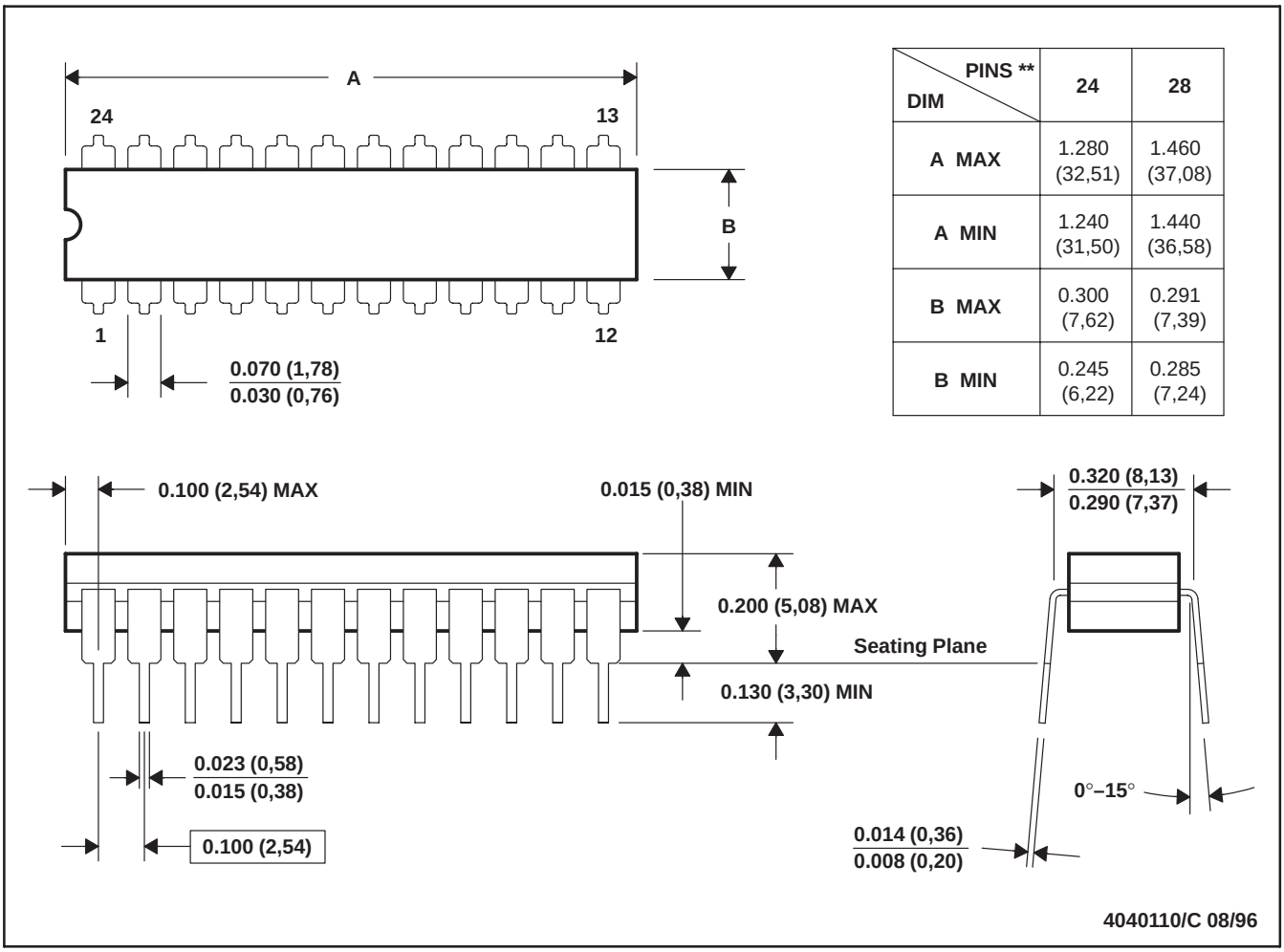
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74ALS646ADW	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN74ALS648ADW	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN74AS646DW	DW	SOIC	24	25	506.98	12.7	4826	6.6

MCER004A – JANUARY 1995 – REVISED JANUARY 1997

JT (R-GDIP-T)** **CERAMIC DUAL-IN-LINE**

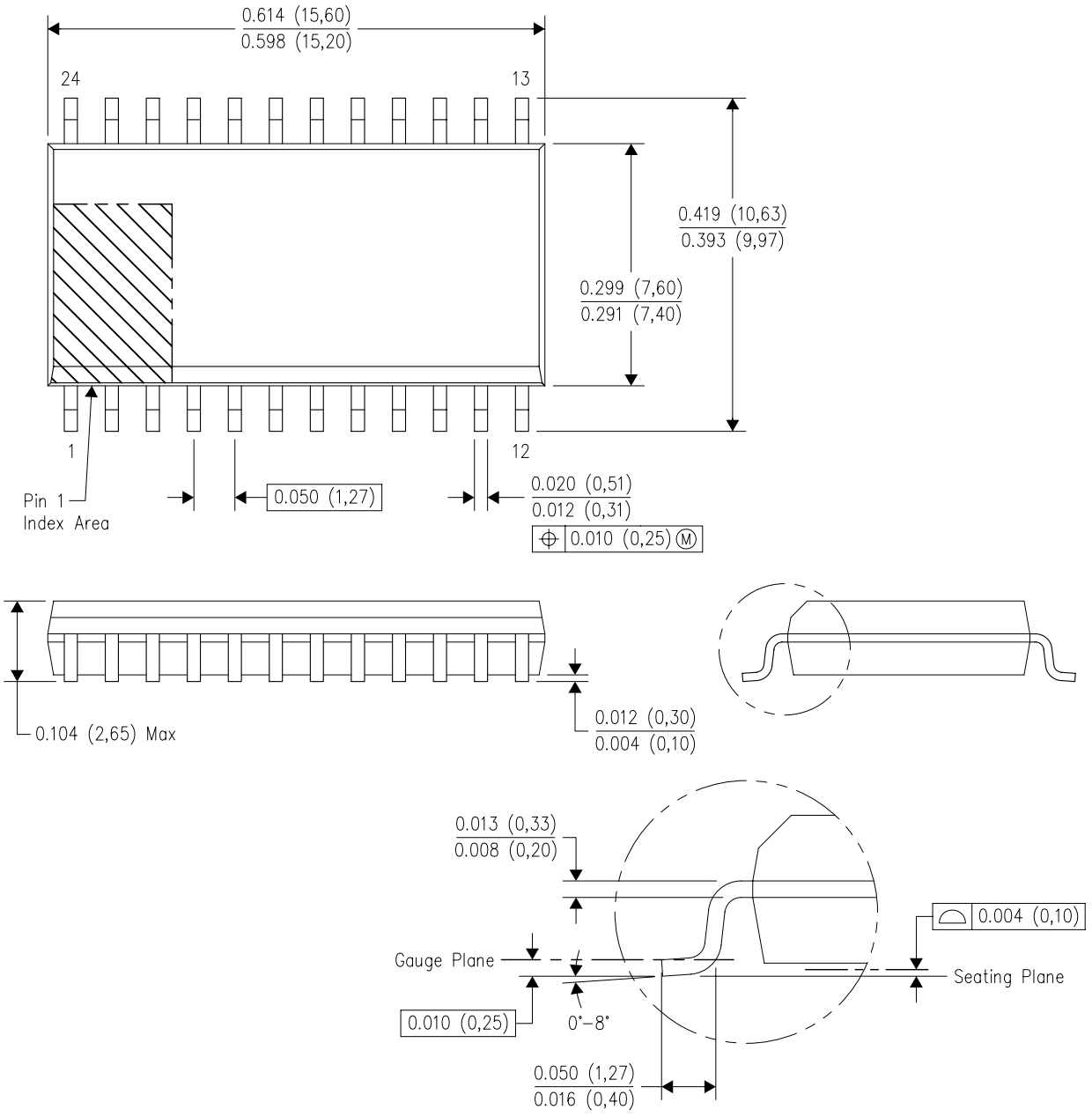
24 LEADS SHOWN



DIM \ PINS **	24	28
A MAX	1.280 (32,51)	1.460 (37,08)
A MIN	1.240 (31,50)	1.440 (36,58)
B MAX	0.300 (7,62)	0.291 (7,39)
B MIN	0.245 (6,22)	0.285 (7,24)

NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification.
E. Falls within MIL STD 1835 GDIP3-T24, GDIP4-T28, and JEDEC MO-058 AA, MO-058 AB

DW (R–PDSO–G24) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
D. Falls within JEDEC MS–013 variation AD.

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